TOSHIBA GTR Module Silicon N Channel IGBT

# MG200Q1ZS40

### High Power Switching Applications Motor Control Applications

• High input impedance

• High speed :  $t_f = 0.5 \mu s$  (Max.)

 $t_{rr} = 0.5 \mu s$  (Max.)

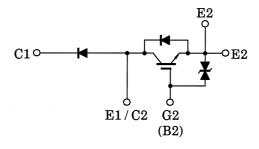
• Low saturation voltage

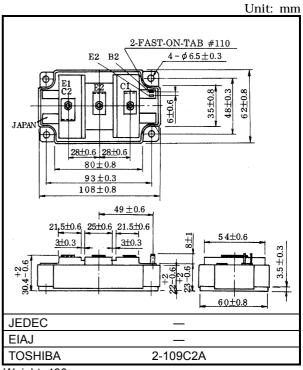
: VCE (sat) = 4.0V (Max.)

• Enhancement-mode

• The electrodes are isolated from case

#### **Equivalent Circuit**





Weight: 430g

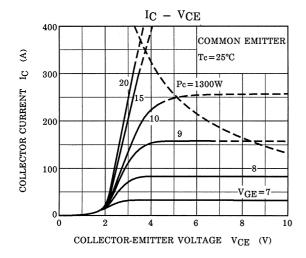
#### **Maximum Ratings (Ta = 25°C)**

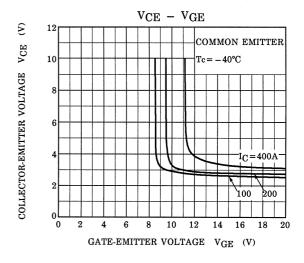
Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V <sub>CES</sub>	1200	V	
Gate-emitter voltage		V <sub>GES</sub>	±20	V	
Collector current	DC	Ic	200	Α	
	1ms	I <sub>CP</sub>	400		
Forward current	DC	l <sub>F</sub>	200	Α	
	1ms	I <sub>FM</sub>	400		
Collector power dissipation (Tc = 25°C)		P <sub>C</sub>	1300	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-40 ~ 125	°C	
Isolation voltage		V <sub>Isol</sub>	2500 (AC 1 min.)	<b>V</b>	
Screw torque (Terminal / mounting)		_	3/3	N·m	

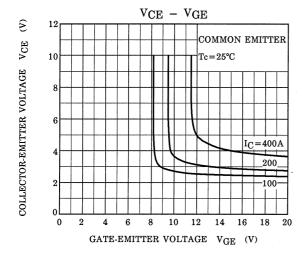
## Electrical Characteristics (Ta = 25°C)

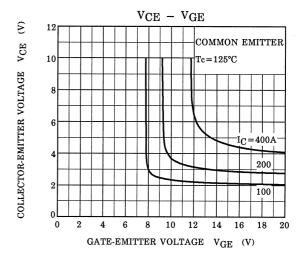
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	V <sub>GE</sub> = ±20V, V <sub>CE</sub> = 0	_	_	±20	μΑ
Collector cut-off current		I <sub>CES</sub>	V <sub>CE</sub> = 1200V, V <sub>GE</sub> = 0	_	_	2.0	mA
Gate-emitter cut-off voltage		V <sub>GE (off)</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 200mA	3.0	_	6.0	V
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 200A, V <sub>GE</sub> = 15V	_	3.0	4.0	V
Input capacitance		C <sub>ies</sub>	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0, f = 1MHz	_	24000	_	pF
Switching time	Rise time	t <sub>r</sub>	15V 4.7Ω 5 600V	_	0.3	0.6	μs
	Turn-on time	t <sub>on</sub>		_	0.4	0.8	
	Fall time	t <sub>f</sub>		_	0.2	0.5	
	Turn-off Time	t <sub>off</sub>		_	0.8	1.5	
Forward voltage		V <sub>F</sub>	I <sub>F</sub> = 200A, V <sub>GE</sub> = 0	_	2.0	3.0	V
Reverse recovery time		t <sub>rr</sub>	I <sub>F</sub> = 200A, V <sub>GE</sub> = -10V di / dt = 300A / μs	_	0.25	0.5	μs
Thermal resistance	Transistor	R <sub>th (j-c)</sub>		_	_	0.096	°C/W
	Diode			_	_	0.25	C/W

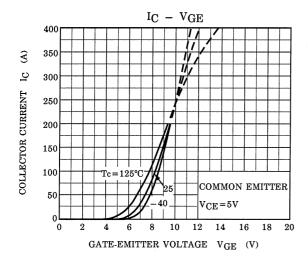
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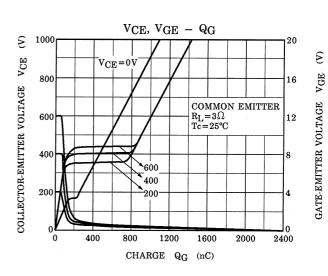




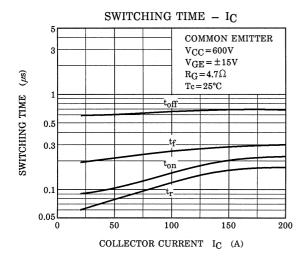


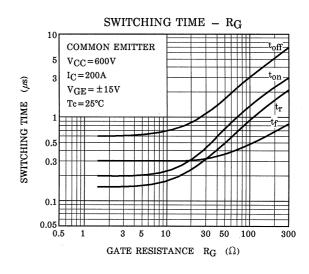


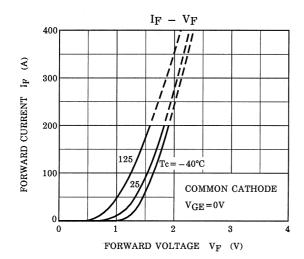


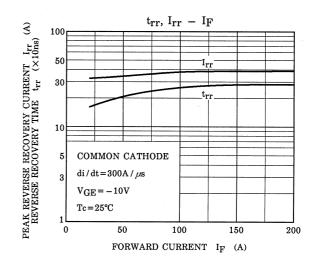


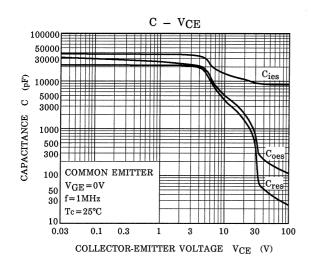
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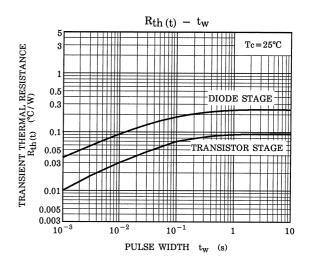




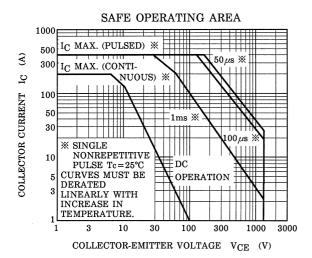


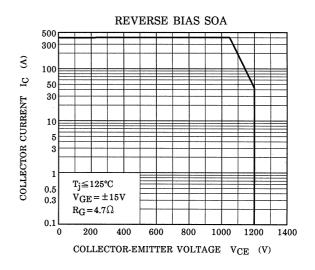






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